





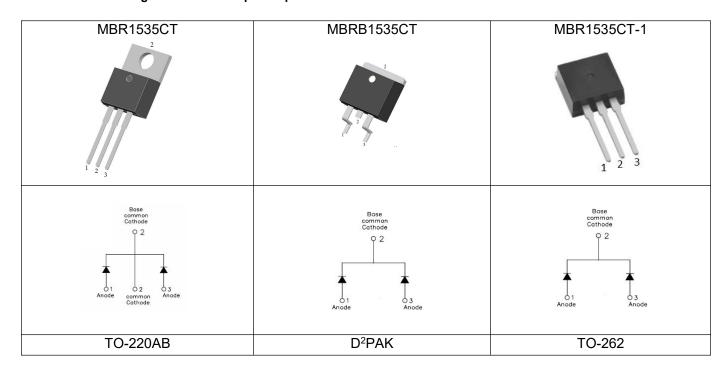
# MBR1535CT/MBRB1535CT/MBR1535CT-1 SCHOTTKY RECTIFIER

#### **Features**

- 150 °C T<sub>J</sub> operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: 100% Pure Tin
- This is a Pb Free Device
- . All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection



## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	35	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=125°C, rectangular wave form	7.5(Per Leg) 15(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	180	Α

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## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V <sub>F1</sub>	@ 15A, Pulse, T <sub>J</sub> = 25 °C	0.65	0.84	V
(Per Leg)*	$V_{F2}$	@ 15A, Pulse, T <sub>J</sub> = 125 °C	0.60	0.72	V
Reverse Current (Per Leg)*	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25  ^{\circ}\text{C}$	0.01	1.0	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 125 ^{\circ}\text{C}$	5	15	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	360	400	pF
Typical Series Inductance (Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

 $<sup>^*</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2%

## **Thermal-Mechanical Specifications:**

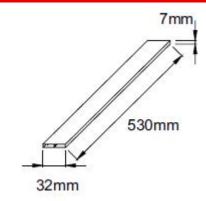
Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	R <sub>θJC</sub>	DC operation	3.0	°C/W
Typical Thermal Resistance, Junction to Case(Per package)	$R_{\theta JA}$	DC operation	60	°C/W
Typical Thermal Resistance, Case to Heat Sink	R <sub>0</sub> CS	Mounting surface, smooth and greased	0.50	°C/W
Case Style	TO-220AB D <sup>2</sup> PAK TO-262			

# **Tube Specification**

Device	Package	Weight	Shipping
MBR1535CT	TO-220AB	1.8g	50pcs / tube
MBRB1535CT	D <sup>2</sup> PAK	1.85g	800pcs / reel
MBRB1535CTTR	D <sup>2</sup> PAK	1.85g	800pcs / reel
MBR1535CT-1	TO-262	1.85g	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# **Tube Specification(TO-220AB/TO-262)**



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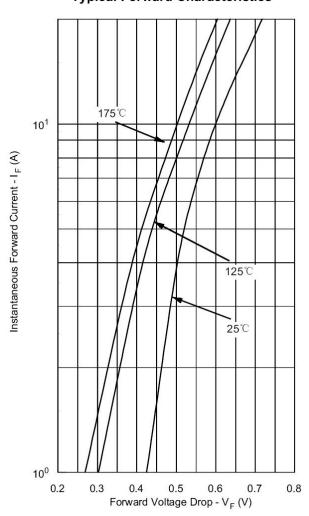




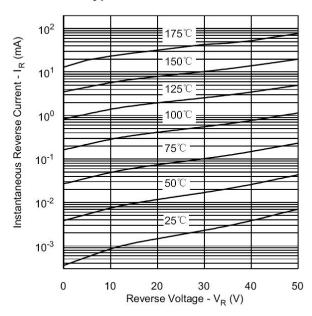


## **Ratings and Characteristics Curves**

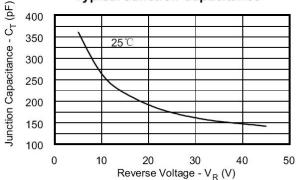
## **Typical Forward Characteristics**



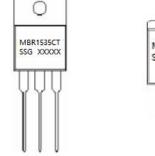
### **Typical Reverse Characteristics**

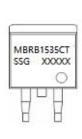


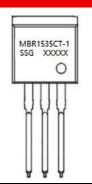
#### **Typical Junction Capacitance**



## **Marking Diagram**







#### Where XXXXX is YYWWL

 MBR
 = Device Type

 B
 = Package type

 15
 = Forward Current (15A)

 35
 = Reverse Voltage (35V)

 CT-1
 = Configuration

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

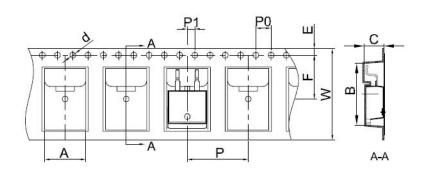
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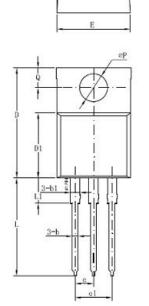


# **Carrier Tape Specification D2PAK**

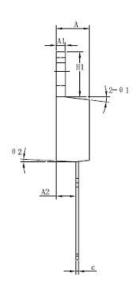


Symbol	Millimeters		
	Min.	Max.	
A	10.70	10.90	
В	16.03	16.23	
С	5.11	5.31	
d	1.45	1.65	
Е	1.65	1.85	
F	11.40	11.60	
P0	3.90	4.10	
Р	15.90	16.10	
P1	1.90	2.10	
W	23.90	24.30	

# **Mechanical Dimensions TO-220AB**



27 0 3



Symbol	Millimeters			
	Min.	Typical	Max.	
Α	4.42	4.57	4.72	
A1	1.17	1.27	1.37	
A2	2.52	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
E	10.01	10.16	10.31	
е		2.54		
e1	4.98	5.06	5.18	
H1	6.04	6.24	6.44	
L	12.7	13.56	13.80	
L1	3.56	3.5	3.96	
ФР	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7°		
Θ2		3°		
Θ3		4°		

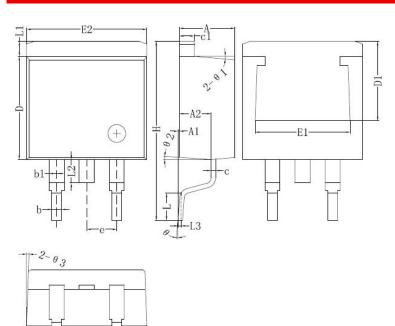
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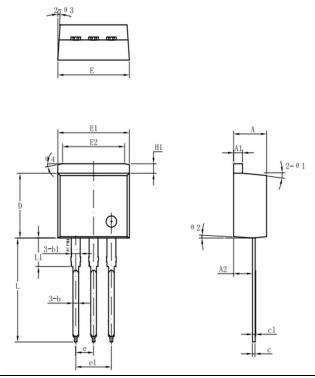


## **Mechanical Dimensions D<sup>2</sup>PAK**



Symbol	Millimeters			
	Min.	Typical	Max.	
Α	4.47	4.70	4.85	
A1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.17	1.27	1.37	
С	0.31	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.50	8.70	8.90	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.31	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.74	
L1	1.12	1.27	1.42	
L2	1.30		2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		4°		
e3		4°		

# **Mechanical Dimensions TO-262**



Symbol	Millimeters			
	Min.	Typical	Max.	
Α	4.55	4.70	4.85	
<b>A</b> 1	0	0.10	0.25	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
c1	1.17	1.27	1.37	
D	8.55	8.70	8.85	
D1	6.40			
E	10.01	10.16	10.31	
E1	7.6			
E2	9.98	10.08	10.18	
е		2.54		
Н	14.6	15.1	15.6	
L	2.00	2.30	2.70	
L1	1.17	1.27	1.40	
L2			2.20	
L3		0.25BSC		
е	0	-	8°	
e1		5°		
e2		4°		
е3		4°		

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#### Technical Data Data Sheet N2263, Rev. -





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